1.

a) For conservation of total energy,

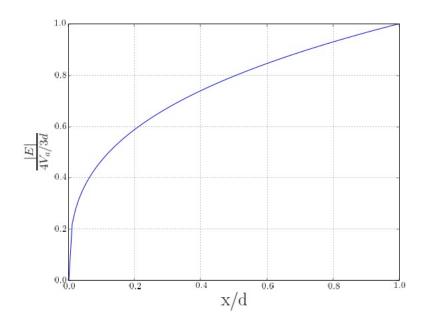
$$\frac{1}{2}m_e v_e^2 = e V(x)$$

Rearranging the above equation, we get,

$$v_e = \sqrt{\frac{2eV(x)}{m_e}} = \sqrt{\frac{2eV_a(x/d)^{\frac{4}{3}}}{m_e}} = 8.39 \times 10^5 \left(\frac{x}{d}\right)^{\frac{2}{3}}$$

b) For electric field,

$$\mathbf{E} = -\nabla V = -\frac{4V_a}{3} \left(\frac{x}{d^4}\right)^{\frac{1}{3}} \hat{x}$$

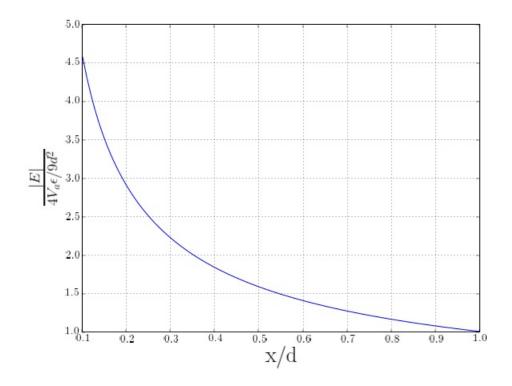


c) Using differential form of Gauss' Law,

$$\rho = \nabla \cdot \mathbf{D} = -\frac{4\epsilon_o V_a}{9d^{\frac{4}{3}}} (x)^{-\frac{2}{3}}$$

Alternatively, Poisson's Equation can be used,

$$\rho = -\epsilon_o \nabla^2 V = -\frac{4\epsilon_o V_a}{9d^{\frac{4}{3}}} (x)^{-\frac{2}{3}}$$



d) The normal component of the displacement field \mathbf{D} changes by an amount equal to the surface charge density at the anode.

$$\rho_s = \mathbf{D}.\hat{n}|_{x=d} = D_x|_{x=d})$$
$$= \frac{8\epsilon_o}{3d} \frac{C}{m^2}$$

2. In electrostatics, we generate a curl-free vector field $\mathbf{E}(x,y,z)$ if we take the gradient of a scalar function V(x,y,z). Therefore, $\nabla \times \mathbf{E} = \nabla \times (-\nabla V) = 0$. Alternatively, we can go through the calculation,

$$\mathbf{E} = -\nabla V = -\nabla (z^2 - yz) = z\hat{y} + (y - 2z)\hat{z}$$

$$\nabla \times \mathbf{E} = \begin{vmatrix} \hat{x} & \hat{y} & \hat{z} \\ \frac{\partial}{\partial x} & \frac{\partial}{\partial y} & \frac{\partial}{\partial z} \\ 0 & z & y - 2z \end{vmatrix} = 0$$

3. Starting with the left-handside of $\nabla \times (\nabla \times \mathbf{A}) = \nabla (\nabla \cdot \mathbf{A}) - \nabla^2 \mathbf{A}$, we write

$$\nabla \times (\nabla \times \mathbf{A}) = \nabla \times \begin{vmatrix} \hat{x} & \hat{y} & \hat{z} \\ \frac{\partial}{\partial x} & \frac{\partial}{\partial y} & \frac{\partial}{\partial z} \\ x + z & 2x + y & 4 \end{vmatrix}$$
$$= \nabla \times (\hat{y} + 2\hat{z}) = 0.$$

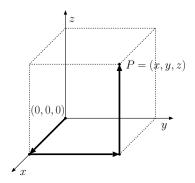
Solving the right-handside of the equation, we obtain

$$\nabla (\nabla \cdot \mathbf{A}) - \nabla^2 \mathbf{A} = \nabla (\nabla \cdot ((x+z)\hat{x} + (2x+y)\hat{y} + 4\hat{y})) - \nabla^2 ((x+z)\hat{x} + (2x+y)\hat{y} + 4\hat{y})$$
$$= \nabla (2) - \mathbf{0} = \mathbf{0}.$$

Consequently, we can see that $\nabla \times (\nabla \times \mathbf{A}) = \nabla (\nabla \cdot \mathbf{A}) - \nabla^2 \mathbf{A}$ is verified since both sides have the same solutions.

4.

a) Since the given field satisfies $\nabla \times \mathbf{E} = 0$, it is said to be an electrostatic field which can be indicated as $\mathbf{E} = -\nabla V$. Thus, the electrostatic potential V at any point P = (x, y, z) can be calculated by performing a vector line integral by using the path shown in the below figure.



Therefore, we can write

$$V(P) - V(0) = -\int_{0}^{P} \mathbf{E} \cdot d\mathbf{l}$$

$$= -\int_{0}^{x} E_{x}(x, 0, 0) dx - \int_{0}^{y} E_{y}(x, y, 0) dy - \int_{0}^{z} E_{z}(x, y, z) dz$$

$$= \frac{x^{2}}{2} - \frac{4}{\pi} (1 - \cos(\frac{\pi y}{4})) - \frac{2z^{3}}{3} V.$$

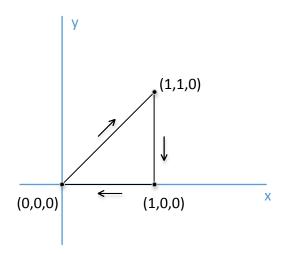
Given that V(0) = 0 V, the electrostatic potential at P = (1, 2, 3) is $V(1, 2, 3) = -\frac{4}{\pi} - \frac{35}{2}$ V.

b) Using differential form of Gauss' Law,

$$\rho = \nabla \cdot \mathbf{D} = \epsilon_o (4z + \frac{\pi}{4} \cos(\frac{\pi y}{4}) - 1)$$

At (0,0,0), $\rho = (\frac{\pi}{4} - 1)\epsilon_o$ and at (1,2,3), $\rho = 11\epsilon_o$.

5. The triangular path defined in the problem is sketched in the below figure.



Referring to the hint given in the problem, we can write

$$\oint_C \mathbf{E} \cdot d\mathbf{l} = \int_{l_1} \mathbf{E}(x, x, 0) \cdot d\mathbf{l}_1 + \int_{l_2} \mathbf{E}(1, y, 0) \cdot d\mathbf{l}_2 + \int_{l_3} \mathbf{E}(x, 0, 0) \cdot d\mathbf{l}_3.$$

Evaluating this equation for the field \mathbf{E} with the - sign, we obtain

$$\oint_C \mathbf{E_1} \cdot d\mathbf{l} = \int_0^1 (\hat{x}x - \hat{y}x) \cdot (\hat{x} + \hat{y}) \, dx - \int_0^1 (\hat{x}y - \hat{y}) \cdot (\hat{y}) \, dy - \int_0^1 (-\hat{y}x) \cdot (\hat{x}) \, dx = 1 \, \text{V}.$$

Likewise, we calculate

$$\oint_C \mathbf{E_2} \cdot d\mathbf{l} = \int_0^1 (\hat{x}x + \hat{y}x) \cdot (\hat{x} + \hat{y}) \, dx - \int_0^1 (\hat{x}y + \hat{y}) \cdot (\hat{y}) \, dy - \int_0^1 (\hat{y}x) \cdot (\hat{x}) \, dx = 0 \, V$$

for the field \mathbf{E} with the + sign. The solution can be double checked by calculating the curls of the electric fields,

$$\nabla \times \mathbf{E_1} = -2\hat{z} \quad \nabla \times \mathbf{E_2} = 0$$

As expected, fields with zero circulation are curl free.

6.

a) One of the boundary conditions state that at any surface S, the normal component of the displacement field \mathbf{D} can change by an amount equal to the surface charge density. Applying this boundary condition to the interface at $y=6\,\mathrm{m}$, the surface charge density is calculated as

$$\rho_s = \hat{y} \cdot (\mathbf{D}|_{y=6^+} - \mathbf{D}|_{y=6^-})$$
$$= 2\epsilon_o - 4\epsilon_o = -2\epsilon_o \frac{\mathbf{C}}{\mathbf{m}^2}.$$

b) Another boundary condition also states that the tangential component of electric field \mathbf{E} needs to be continuous along the surface S. Therefore, we can write

$$E_x|_{y=6^+} = E_x|_{y=6^-}$$
,

Given that the space is vacuum, we can verify that $D_x|_{y=6^+} = D_x|_{y=6^-} = 2\epsilon_o \frac{\text{C}}{\text{m}^2}$. Consequently, the displacement field **D** for the region y > 6 m can be expressed as

$$\mathbf{D} = 2\epsilon_o \hat{x} + 2\epsilon_o \hat{y} \frac{\mathbf{C}}{\mathbf{m}^2}.$$

c) Looking at the charge distribution, one can see that there is a charge density of $6\epsilon_0 \,\mathrm{C/m}^2$ along the interface at y=0. Thus, applying boundary conditions, we can write

$$\rho_s = \hat{y} \cdot (\mathbf{D} \big|_{y=0^+} - \mathbf{D} \big|_{y=0^-}),$$

from which we obtain $D_y|_{y=0^-} = 4\epsilon_o - 6\epsilon_o \frac{C}{m^2}$. Given that the space is vacuum, we can also verify that $D_x|_{y=0^+} = D_x|_{y=0^-} = 2\epsilon_o \frac{C}{m^2}$. Consequently, the displacement field **D** for the region y < 0 can be expressed as

$$\mathbf{D} = 2\epsilon_o \hat{x} - 2\epsilon_o \hat{y} \, \frac{\mathbf{C}}{\mathbf{m}^2}.$$

d) The displacement field, **D**, is defined to be equal to $\epsilon_{medium} \mathbf{E}$. Since the region is in free space $\epsilon_{medium} = \epsilon_0$, the electric field in the region where y < 0 m is

$$\mathbf{E} = \frac{\mathbf{D}}{\epsilon_0} = \frac{2\epsilon_o \hat{x} - 2\epsilon_o \hat{y}}{\epsilon_0} = 2\hat{x} - 2\hat{y} \frac{V}{m}$$

The electric field in the region where 0 < y < 6 m is

$$\mathbf{E} = \frac{\mathbf{D}}{\epsilon_0} = \frac{2\epsilon_o \hat{x} + 4\epsilon_o \hat{y}}{\epsilon_0} = 2\hat{x} + 4\hat{y} \frac{V}{m}$$

The electric field in the region where y > 6 m is

$$\mathbf{E} = \frac{\mathbf{D}}{\epsilon_0} = \frac{2\epsilon_0 \hat{x} + 2\epsilon_0 \hat{y}}{\epsilon_0} = 2\hat{x} + 2\hat{y} \frac{V}{m}$$

e) The voltage drop from a point P (y = 0) to ground O (y = 6) can be calculated as follows,

$$V = \int_{p}^{O} \mathbf{E} \cdot d\mathbf{l} = \int_{0}^{6} (2\hat{x} + 4\hat{y}) \cdot d\hat{y} = \int_{0}^{6} 4 \, dz = 24 \, V$$

f) If the medium in the region 0 < y < 6 m was replaced with a dielectric with permittivity $\epsilon_{medium} = 4\epsilon_0$, it will only affect equations that deal with the electric field in this middle region since $\mathbf{E} = \frac{\mathbf{D}}{4\epsilon_0}$ now (only part a will remain unchanged). Parts b and c all are solved knowing that tangential electric field boundary conditions are continuous, and thus there will be a change in the displacement field here. Part d will change as it asks to compute the electric field in this region. Part e will also change since the voltage drop is desired in this region and it is calculated by integrating along the electric field.

- 7.
- a) In vacuum, the displacement vector is $\mathbf{D} = \epsilon_o \mathbf{E} + \mathbf{P}$. Thus, the displacement field between the plates is

$$\mathbf{D} = 4\epsilon_o \hat{z} \, \frac{\mathbf{C}}{\mathbf{m}^2},$$

from which we obtain the polarization field as $\mathbf{P} = 0 \frac{C}{m^2}$.

b) Since $\mathbf{D} = \mathbf{0}$ for z < 0, i.e. $\mathbf{D}|_{z=0^-}$ the surface charge on the plate at z = 0 is

$$\rho_s|_{z=0} = \hat{z} \cdot (\mathbf{D}|_{z=0^+} - \mathbf{D}|_{z=0^-}) = 4\epsilon_o \frac{C}{m^2}.$$

c) If the gap is filled with a dielectric of permittivity $\epsilon = 87\epsilon_o$ without changing the surface charge density then the displacement field will remain the same, i.e.,

$$\mathbf{D} = 4\epsilon_o \,\hat{z} \, \frac{\mathbf{C}}{\mathbf{m}^2}.$$

But, the electric field is now

$$\mathbf{E} = \frac{1}{\epsilon} \mathbf{D} = \frac{4}{87} \,\hat{z} \, \frac{\mathbf{V}}{\mathbf{m}}.$$

Consequently, the polarization field becomes

$$\mathbf{P} = \mathbf{D} - \epsilon_o \mathbf{E} = \frac{344}{87} \epsilon_o \,\hat{z} \, \frac{\mathbf{C}}{\mathbf{m}^2}.$$

- d) If the medium in the gap has a finite conductivity, then it will also have $\mathbf{E}=0$ in "steady-state". Thus, $\mathbf{D} \to 0$ and $\mathbf{P} \to 0$. Because, the mobile free charges within the medium in the gap will be pushed and pulled to pile up at the surfaces until the surface charge density generates a secondary field that cancels out the fields within the medium. In this particular case, the salt water shorts out the original field between the plates.
- 8. The solution of the problem will be given region by region.
 - The region defined by $r \leq a$ is occupied by a conductor with $\sigma = 10^5 \, \mathrm{S/m}$, therefore, we can directly write

$$\mathbf{D} = \mathbf{0} \frac{\mathrm{C}}{\mathrm{m}^2}, \qquad \mathbf{E} = \mathbf{0} \frac{\mathrm{V}}{\mathrm{m}}, \qquad \mathbf{P} = \mathbf{0} \frac{\mathrm{C}}{\mathrm{m}^2}.$$

for this particular region. In steady-state, charges can accumulate only on the surface of conducting materials. Since this material holds a net charge per unit length $Q=4\frac{C}{m}$, the surface charge density at radius r=a is

$$\rho_s|_{r=a} = \frac{Q}{Circumference} = \frac{4}{2\pi a} = \frac{2}{\pi a} \frac{\mathbf{C}}{\mathbf{m}^2}.$$

• The region defined by a < r < b is occupied by a dielectric with $\epsilon = 4\epsilon_o$. Applying Gauss's law $\oint \mathbf{D} \cdot d\mathbf{S} = \int_V \rho dV = Q_{enc}$ and considering $\mathbf{D} = D_r \hat{r}$, we find

$$D.(2\pi rL) = Q_{enc} = 4 \times L$$

$$\mathbf{D} = \frac{4}{2\pi r}\hat{r} = \frac{2}{\pi r}\hat{r}\frac{\mathbf{C}}{\mathbf{m}^2}$$

for a < r < b. Hence, the electric field **E** is

$$\mathbf{E} = \frac{\mathbf{D}}{\epsilon} = \frac{1}{2\epsilon_o \pi r} \hat{r} \frac{V}{\mathbf{m}},$$

from which we can obtain the polarization P as

$$\mathbf{P} = \mathbf{D} - \epsilon_o \mathbf{E} = (\frac{1}{\pi r} - \frac{1}{2\pi r})\hat{r} = \frac{3}{2\pi r}\hat{r} \frac{\mathbf{C}}{\mathbf{m}^2}.$$

• As the region defined by $b \leq r \leq c$ has the same material properties as region $r \leq a$, we can write

$$\mathbf{D} = \mathbf{0} \frac{\mathrm{C}}{\mathrm{m}^2}, \qquad \mathbf{E} = \mathbf{0} \frac{\mathrm{V}}{\mathrm{m}}, \qquad \mathbf{P} = \mathbf{0} \frac{\mathrm{C}}{\mathrm{m}^2}.$$

Then, the surface charge density at r = b is given by

$$\begin{aligned} \rho_s|_{r=b} &= \hat{r}.(\mathbf{D}|_{r=b^+} - \mathbf{D}|_{r=b^-})|_{r=b} \\ &= \hat{r}\cdot\left(-\frac{2}{\pi r}\hat{r}\right)\Big|_{r=b} = -\frac{2}{\pi b}\frac{\mathbf{C}}{\mathbf{m}^2}. \end{aligned}$$

• The region defined by $c \le r \le d$ is occupied by a dielectric with $\epsilon = 2\epsilon_o$. Since the net charge per unit length is $4 - 2 = 2\frac{C}{m}$, the surface charge density at radius r = c is

$$\rho_s|_{r=c} = \frac{Q}{\text{Circumference}} = \frac{2}{2\pi c} = \frac{1}{\pi c} \frac{\text{C}}{\text{m}^2}.$$

Applying Gauss's law $\oint \mathbf{D} \cdot d\mathbf{S} = \int_V \rho dV = Q$ and considering $\mathbf{D} = D_r \hat{r}$, we find

$$\mathbf{D} = \frac{2}{2\pi r}\hat{r} = \frac{1}{\pi r}\hat{r}\frac{\mathbf{C}}{\mathbf{m}^2}$$

for c < r < d. Hence, the electric field **E** is

$$\mathbf{E} = \frac{\mathbf{D}}{\epsilon} = \frac{1}{2\epsilon_o \pi r} \hat{r} \frac{V}{\mathbf{m}},$$

from which we can obtain the polarization P as

$$\mathbf{P} = \mathbf{D} - \epsilon_o \mathbf{E} = (\frac{1}{\pi r} - \frac{1}{2\pi r})\hat{r} = \frac{1}{2\pi r}\hat{r} \frac{\mathbf{C}}{\mathbf{m}^2}.$$

• Region defined by r > d is free space. Applying Gauss' law and noting that the total charge per unit length enclosed is $2\frac{C}{m}$, we get $\oint \mathbf{D} \cdot d\mathbf{S} = Q = 2 \times L\frac{C}{m}$ where $d\mathbf{S} = \hat{r}2\pi r$. Therefore, we can write

$$\mathbf{D} = \frac{1}{\pi r} \hat{r} \frac{\mathbf{C}}{\mathbf{m}^2}, \qquad \mathbf{E} = \frac{1}{\pi \epsilon_0 r} \hat{r} \frac{\mathbf{V}}{\mathbf{m}}, \qquad \mathbf{P}_4 = \mathbf{0} \frac{\mathbf{C}}{\mathbf{m}^2}.$$

Consequently, the surface charge density at r = d is given by

$$\rho_s|_{r=d} = \hat{r}.(\mathbf{D}|_{r=d^+} - \mathbf{D}|_{r=d^-})|_{r=d}$$
$$= 0 \frac{C}{m^2}.$$

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- 9.
- a) The total potential at a point P can be given as follows,

$$V = \frac{Q}{4\epsilon_0\pi r_+} - \frac{Q}{4\epsilon_0\pi r_-}$$

where $r_{\pm}^2 = r^2 + a^2 \pm 2ra\cos(\theta)$. Using binomial approximation $(1+p)^n \approx 1 + np$ and assuming r >> a, $\frac{1}{r}$ can be approximated as follows,

$$\frac{1}{r_{\pm}} = \frac{1}{r} [1 + (\frac{a}{r})^2 \pm 2(\frac{a}{r})\cos(\theta)]^{-\frac{1}{2}}$$
$$= \frac{1}{r} [1 - \frac{1}{2}(\frac{a}{r})^2 \mp (\frac{a}{r})\cos(\theta) + \dots]$$

Taking the first three terms and substituting back into the potential,

$$\begin{split} V &\approx \frac{Q}{4\epsilon_0\pi r}[1-\frac{1}{2}(\frac{a}{r})^2-(\frac{a}{r})\cos(\theta)-1+\frac{1}{2}(\frac{a}{r})^2-(\frac{a}{r})\cos(\theta)]\\ &= \frac{Q}{4\epsilon_0\pi r}[-2(\frac{a}{r})\cos(\theta)]=\frac{-2Qa\cos(\theta)}{4\epsilon_0\pi r^2} \end{split}$$

b) The electric field lines(red) and the equipotential planes(blue) can be graphed as follows,

